

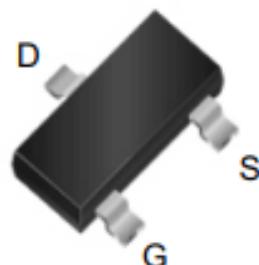
SSC8017GS6A

P-Channel Enhancement Mode MOSFET

➤ Features

V_{DS}	V_{GS}	$R_{DS(ON)}\text{ Typ.}$	I_D
-12V	$\pm 8V$	14m Ω @-4V5	-11A
		21m Ω @-2V5	
		34m Ω @-1V8	

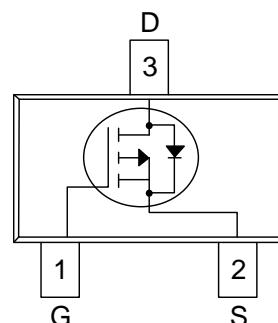
➤ Pin configuration



SOT-23-3L

➤ Description

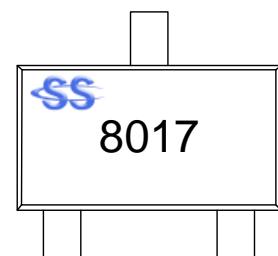
The SSC8017GS6A is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent RDSON with low gate charge. This device is suitable for use in load switch, electronic cigarette and Battery Isolation.



Pin Configuration (Top View)

➤ Applications

- Load Switch
- Electronic Cigarette
- Battery Isolation



Marking

➤ Ordering Information

Device	Package	Shipping
SSC8017GS6A	SOT-23-3L	3000/Reel

➤ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain-to-Source Voltage	-12	V
V_{GSS}	Gate-to-Source Voltage	± 8	V
I_D	Continuous Drain Current ^a	-11	A
I_{DM}	Pulsed Drain Current ^b	-44	A
P_D	Power Dissipation ^a	2.8	W
T_J	Operation junction temperature	-55~150	$^\circ\text{C}$
T_{STG}	Storage temperature range	-55~150	$^\circ\text{C}$

➤ Thermal Resistance Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ^a	45	$^\circ\text{C}/\text{W}$

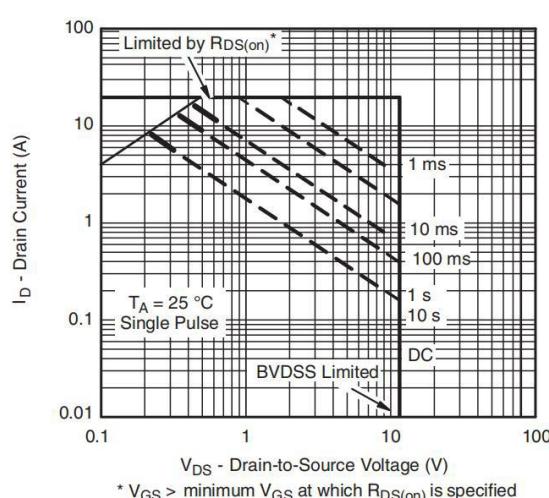
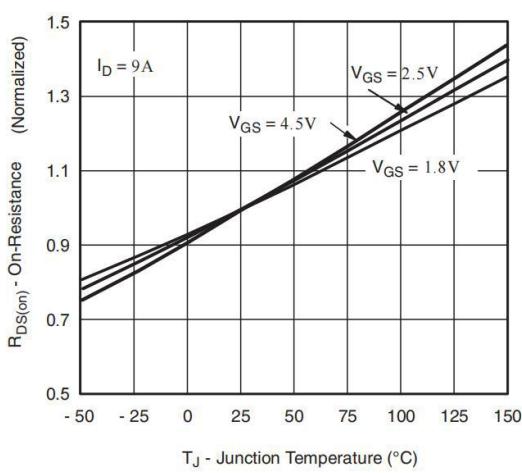
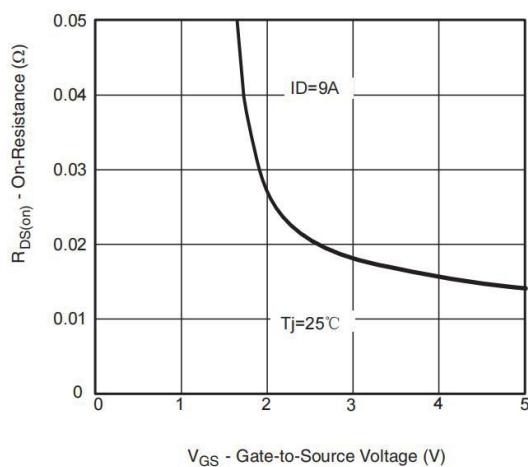
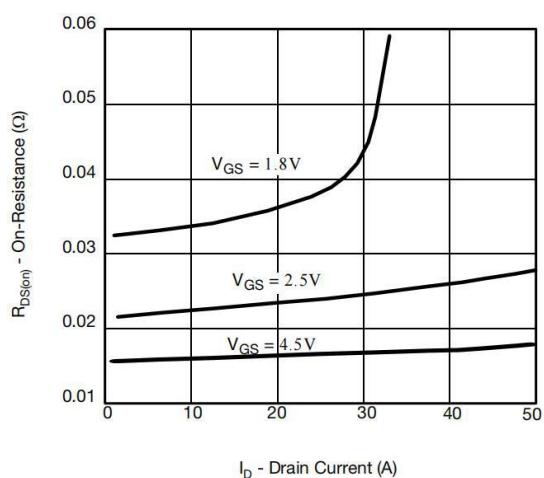
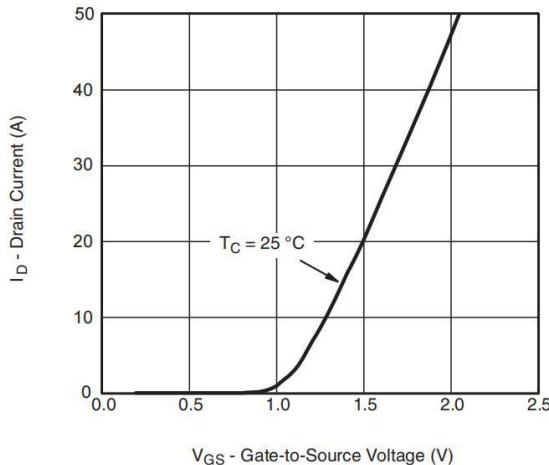
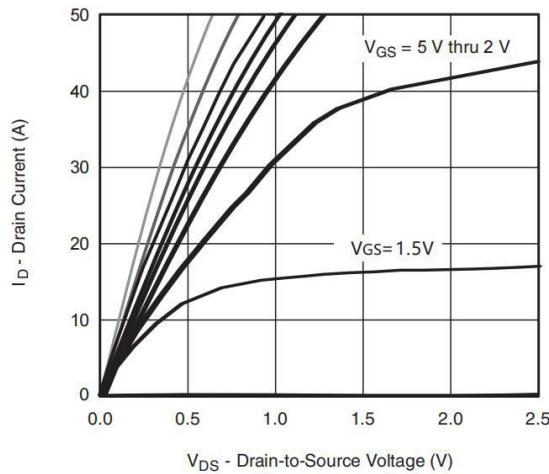
Note:

- a. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2oz.copper, in a still air environment with $T_A=25^\circ\text{C}$. The value in any given application depends on the user's specific board design. The power dissipation is based on the $t \leq 10\text{s}$ thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.

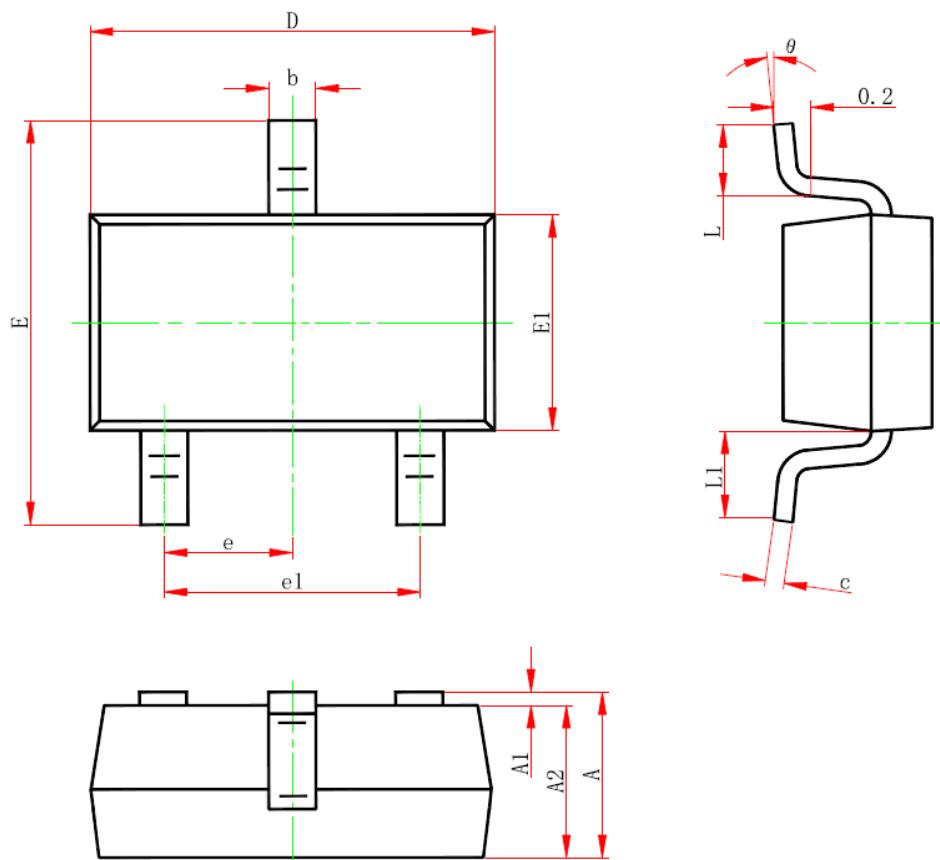
➤ Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-12			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.4	-0.7	-1	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = -4.5V, I_D = -7A$		14	19	$m\Omega$
		$V_{GS} = -2.5V, I_D = -6A$		21	30	
		$V_{GS} = -1.8V, I_D = -4A$		34	50	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -9.6V, V_{GS} = 0V$			-1	μA
Gate-Source Leak Current	I_{GSS}	$V_{GS} = \pm 8V, V_{DS} = 0V$			± 100	nA
Transconductance	G_{FS}	$V_{DS} = -5V, I_D = -5A$		45		s
Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = -2A$			-1.2	V
Input Capacitance	C_{ISS}	$V_{DS} = -7V, V_{GS} = 0V,$ $f = 1MHz$		1620		pF
Output Capacitance	C_{OSS}			380		
Reverse Transfer Capacitance	C_{RSS}			390		
Turn-on Delay Time	$T_{D(ON)}$	$V_{GS} = -4.5V, V_{DS} = -6V,$ $R_L = 2\Omega, R_G = 6\Omega,$ $I_D = -9A$		11.5		ns
Rise Time	T_r			13		
Turn-off Delay Time	$T_{D(OFF)}$			107		
Fall Time	T_f			62		
Total Gate Charge	Q_G	$V_{GS} = -4.5V, V_{DS} = -6V,$ $I_D = -9A$		19		nC
Gate to Source Charge	Q_{GS}			3.5		
Gate to Drain Charge	Q_{GD}			4.6		

➤ Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)



➤ Package Information


Package: SOT-23-3L

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
L1	0.600REF.		0.024REF.	
θ	0°	8°	0°	8°

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